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Electron capture imaging of two-dimensional materials

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Synopsis
The principles of an imaging technique for 2D materials are presented. It is based on the measurement of differential cross sections for electron capture induced by impact of keV-proton on such materials. We illustrate these principles for graphene target and demonstrate the selectivity of this technique upon materials, geometries and surface defects through the highly coherent phenomenon giving rise to the imaging pattern.

Two-dimensional materials, e.g. graphene, designed with spectacular properties, possess an important potential for applications. Aside their macroscopic features, the present possibility to suspend them on boundaries [1] opens rather new lines of studies based on their quantum properties at the atomic level, such as tunneling, specific reactivity in a molecular environment, ... The dynamics response of graphene to strong and ultrafast perturbations is one of these lines and is still largely unexplored nowadays. Concerning laser field interaction theoretical investigations have predicted strong high harmonics generation and formation of focused beam of relativistic electrons [2, 3]. Concerning high-energy ion irradiation attention has been focused on defect formation and hardness properties, e.g. [4, 5]. For low-energy ion-impact a recent investigation [6] simulated images of graphene using the ionization process induced by 30-keV He⁺ impact on single suspended sheet. Based on time-dependent density functional theory a large part of the ultrafast electronic dynamics during the scattering event was ignored.

During the conference, we shall present the principle of a new imaging technique based on electron transfer from the sample to the projectile ion. Our predictions stem from a newly developed approach based on scattering theory state-of-the-art semiclassical non perturbative treatment [7] where the periodicity of the target is taken into account. We shall show that contrasted - atom/site selective - images (cf. Figure 1) can be formed due to coherent mechanisms working on each node of the lattice in a rather narrow domain of impact energies. State-to-state probabilities, energy dependence and geometrical selectivity of the process will be also presented.

A surprising contrast of the images produced by our calculations is observed when comparing to the ion-atom counterpart. A simple and illuminating model will be presented in order to explain the coherent multicenter effect giving rise to this behavior, opening the way to generalize this imaging principle to any periodic two-dimensional materials.

Figure 1. Left: Total electron capture probability as function of impact positions of H⁺ on a semi-infinite graphene surface, perpendicular to the projectile beam. Collision energy is 7.5 keV. Right: same as left but with a single vacancy (missing carbon atom in the lattice).

References

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